

Memory Stick™ INTERCONNECT EXTENDER CHIPSET WITH LVDS

SN65LVDT14 – ONE DRIVER PLUS FOUR RECEIVERS

SN65LVDT41 – FOUR DRIVERS PLUS ONE RECEIVER

FEATURES

- **Controlled Baseline**
 - One Assembly/Test Site, One Fabrication Site
 - **Enhanced Diminishing Manufacturing Sources (DMS) Support**
 - **Enhanced Product-Change Notification**
 - **Qualification Pedigree ⁽¹⁾**
 - **Integrated 110-Ω Nominal Receiver Line Termination Resistor**
 - **Operate From a Single 3.3-V Supply**
 - **Greater Than 125-Mbps Data Rate**
 - **Flow-Through Pinout**
 - **LVTTL-Compatible Logic I/Os**
 - **ESD Protection on Bus Pins Exceeds 12 kV**
 - **Meet or Exceed Requirements of ANSI/TIA/EIA-644A Standard for LVDS**
 - **20-Pin Thin Shrink Small-Outline Package (PW) With 26-Mil Terminal Pitch**
- (1) Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

APPLICATIONS

- **Memory Stick™ Interface Extensions With Long Interconnects Between Host and Memory Stick**
- **Serial Peripheral Interface™ (SPI™) Interface Extension to Allow Long Interconnects Between Master and Slave**
- **MultiMediaCard™ (MMC) Interface in SPI Mode**
- **General-Purpose Asymmetric Bidirectional Communication**

DESCRIPTION

The SN65LVDT14 combines one LVDS line driver with four terminated LVDS line receivers in one package. It is designed to be used at the Memory Stick™ end of an LVDS-based Memory Stick interface extension.

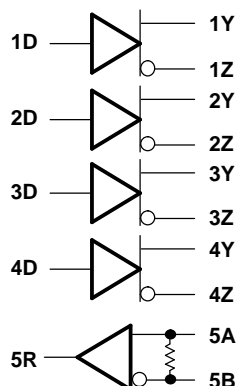
The SN65LVDT41 combines four LVDS line drivers with a single terminated LVDS line receiver in one package. It is designed to be used at the host end of an LVDS-based Memory Stick interface extension.



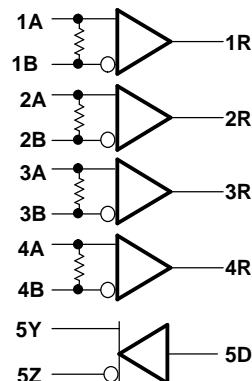
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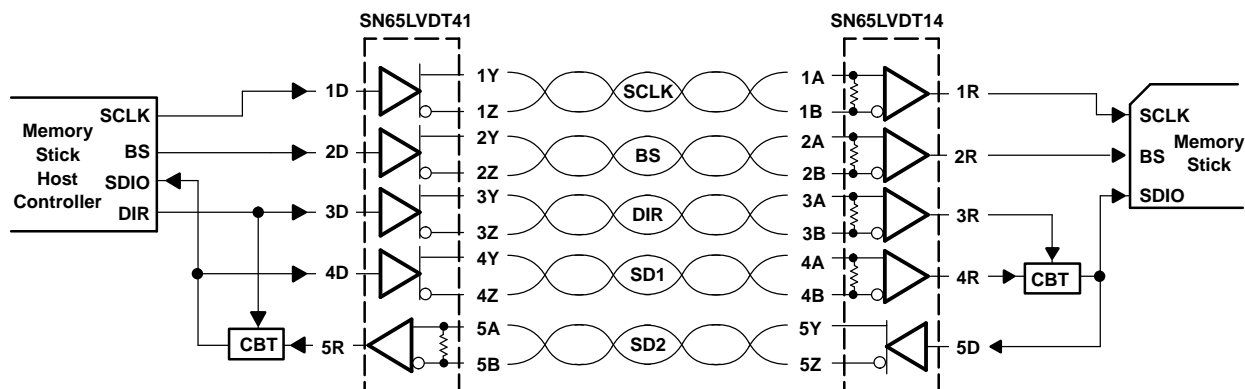
**SN65LVDT41 LOGIC DIAGRAM
(POSITIVE LOGIC)**



**SN65LVDT14 LOGIC DIAGRAM
(POSITIVE LOGIC)**



TYPICAL MEMORY STICK INTERFACE EXTENSION



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

| | | | SN65LVDT14, SN65LVDT41 | | UNIT |
|--|-------------------------------------|---------------------|------------------------------|------|------|
| | | | MIN | MAX | |
| V_{CC} | Supply voltage range ⁽²⁾ | | −0.5 | 4 | V |
| Input voltage range | D or R | | −0.5 | 6 | V |
| | A, B, Y, or Z | | −0.5 | 4 | |
| Electrostatic discharge | Human-Body Model ⁽³⁾ | A, B, Y, Z, and GND | | ±12 | KV |
| | | All pins | | ±8 | |
| | Charged-Device Model ⁽⁴⁾ | All pins | | ±500 | V |
| Continuous total power dissipation | | | See Dissipation Rating Table | | |
| Storage temperature range | | | −65 | 150 | °C |
| Lead temperature 1,6 mm (1/16 in) from case for 10 s | | | | 260 | °C |

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

(3) Tested in accordance with JEDEC Standard 22, Test Method A114-A

(4) Tested in accordance with JEDEC Standard 22, Test Method C101

Package Dissipation Ratings

| PACKAGE | $T_A < 25^\circ\text{C}$ POWER RATING | OPERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$ | $T_A = 85^\circ\text{C}$ POWER RATING | $T_A = 125^\circ\text{C}$ POWER RATING |
|---------|--|--|--|---|
| PW | 774 mW | 6.2 mW/ $^\circ\text{C}$ | 402 mW | 154 mW |

Recommended Operating Conditions

| | | MIN | NOM | MAX | UNIT |
|------------|--|----------------------|----------------------------|-----|------------------|
| V_{CC} | Supply voltage range | 3 | 3.3 | 3.6 | V |
| V_{IH} | High-level input voltage | 2 | | | V |
| V_{IL} | Low-level input voltage | | | 0.8 | V |
| $ V_{ID} $ | Magnitude of differential input voltage | 0.1 | | 0.6 | V |
| V_{IC} | Common-mode input voltage (see Figure 1) | $\frac{ V_{ID} }{2}$ | $2.4 - \frac{ V_{ID} }{2}$ | | V |
| | | | $V_{CC} - 0.8$ | | |
| T_A | Operating free-air temperature | –40 | | 125 | $^\circ\text{C}$ |

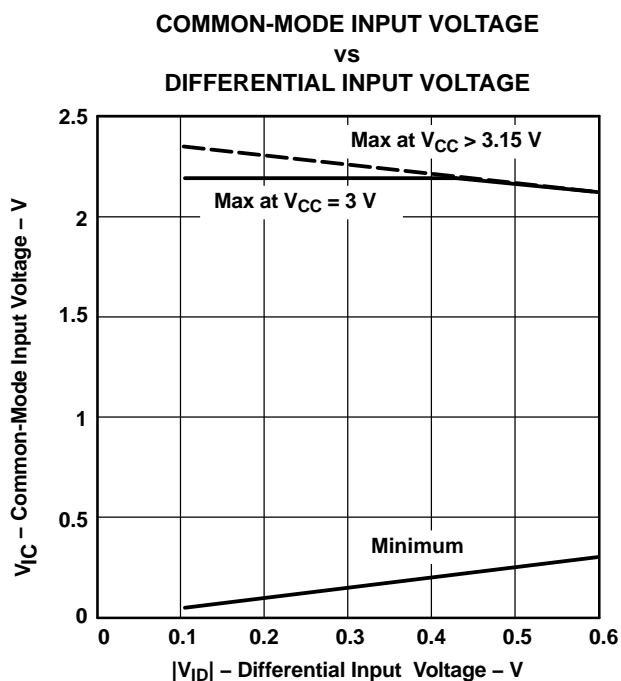


Figure 1. V_{IC} vs V_{ID} and V_{CC}

Receiver Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|--------------|---|--|------|--------------------|-----|------|
| V_{ITH+} | Positive-going differential input voltage threshold | See Figure 2 and Table 1 | | | 100 | mV |
| V_{ITH-} | Negative-going differential input voltage threshold | See Figure 2 and Table 1 | –100 | | | mV |
| V_{OH} | High-level output voltage | $I_{OH} = -8$ mA | 2.4 | | | V |
| V_{OL} | Low-level output voltage | $I_{OL} = 8$ mA | | | 0.4 | V |
| I_I | Input current (A or B inputs) | $V_I = 0$ V and $V_I = 2.4$ V, Other input open | | | ±40 | μA |
| $I_{I(OFF)}$ | Power-off input current (A or B inputs) | $V_{CC} = 0$ V, $V_I = 2.4$ V | | | ±40 | μA |
| C_I | Input capacitance, A or B input to GND | $V_I = A \sin 2\pi ft + CV$ | | 5 | | pF |
| Z_t | Termination impedance | $V_{ID} = 0.4 \sin 2.5E09 t$ V | 88 | | 132 | Ω |

(1) All typical values are at 25°C and with a 3.3-V supply.

Driver Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|---------------------|--|---|-------|--------------------|-------|------|
| $ V_{OD} $ | Differential output voltage magnitude | $R_L = 100$ Ω, See Figure 3 and Figure 5 | 247 | 340 | 454 | mV |
| $\Delta V_{OD} $ | Change in differential output voltage magnitude between logic states | $R_L = 100$ Ω, See Figure 3 and Figure 5 | –50 | | 50 | mV |
| $V_{OC(SS)}$ | Steady-state common-mode output voltage | See Figure 6 | 1.125 | | 1.375 | V |
| $\Delta V_{OC(SS)}$ | Change in steady-state common-mode output voltage between logic states | See Figure 6 | –50 | | 50 | mV |
| $V_{OC(PP)}$ | Peak-to-peak common-mode output voltage | See Figure 6 | | 50 | | mV |
| I_{IH} | High-level input current | $V_{IH} = 2$ V | | | 20 | μA |
| I_{IL} | Low-level input current | $V_{IL} = 0.8$ V | | | 10 | μA |
| I_{OS} | Short-circuit output current | V_{OY} or $V_{OZ} = 0$ V | | | ±24 | mA |
| | | $V_{OD} = 0$ V ⁽²⁾ | | | ±12 | |
| $I_{O(OFF)}$ | Power-off output current | $V_{CC} = 1.5$ V, $V_O = 2.4$ V | | | ±1 | μA |

(1) All typical values are at 25°C and with a 3.3-V supply.

(2) This parameter is GBD over industrial temperature range.

Device Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | MAX | UNIT |
|-----------|----------------|-----------------|--|-----|------|
| I_{CC} | Supply current | SN65LVDT14 | Driver $R_L = 100$ Ω, Driver $V_I = 0.8$ V or 2 V, Receiver $V_I = \pm 0.4$ V | 25 | mA |
| | | SN65LVDT41 | | 35 | |

Receiver Switching Characteristics

over operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | MIN | NOM | MAX | UNIT |
|---|--|------|-----|-----|------|
| t_{PLH} Propagation delay time, low- to high-level output | $C_L = 10 \text{ pF}$, See Figure 4 | 1 | 2.6 | 4.8 | ns |
| t_{PHL} Propagation delay time, high- to low-level output | | 1 | 2.6 | 4.8 | ns |
| t_r Output signal rise time | | 0.15 | | 1.4 | ns |
| t_f Output signal fall time | | 0.15 | | 1.4 | ns |
| $t_{sk(p)}$ Pulse skew ($ t_{PHL} - t_{PLH} $) | | | 150 | 750 | ps |
| $t_{sk(o)}$ Output skew ⁽¹⁾ | | | 100 | 550 | ps |
| $t_{sk(pp)}$ Part-to-part skew ⁽²⁾ | | | | 1 | ns |

- (1) $t_{sk(o)}$ is the magnitude of the time difference between the t_{PLH} or t_{PHL} of all the receivers of a single device with all of their inputs connected together.
- (2) $t_{sk(pp)}$ is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

Driver Switching Characteristics

over operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | MIN | NOM | MAX | UNIT |
|---|--|------|-----|-----|------|
| t_{PLH} Propagation delay time, low- to high-level output | $R_L = 100 \Omega$, $C_L = 10 \text{ pF}$, See Figure 7 | 0.9 | 1.7 | 3.9 | ns |
| t_{PHL} Propagation delay time, high- to low-level output | | 0.9 | 1.6 | 3.9 | ns |
| t_r Differential output signal rise time | | 0.26 | | 1.2 | ns |
| t_f Differential output signal fall time | | 0.26 | | 1.2 | ns |
| $t_{sk(p)}$ Pulse skew ($ t_{PHL} - t_{PLH} $) | | | 150 | 750 | ps |
| $t_{sk(o)}$ Output skew ⁽¹⁾ | | | 80 | 400 | ps |
| $t_{sk(pp)}$ Part-to-part skew ⁽²⁾ | | | | 1.5 | ns |

- (1) $t_{sk(p)}$ is the magnitude of the time difference between the high-to-low and low-to-high propagation delay times at an output.
- (2) $t_{sk(pp)}$ is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

PARAMETER MEASUREMENT INFORMATION

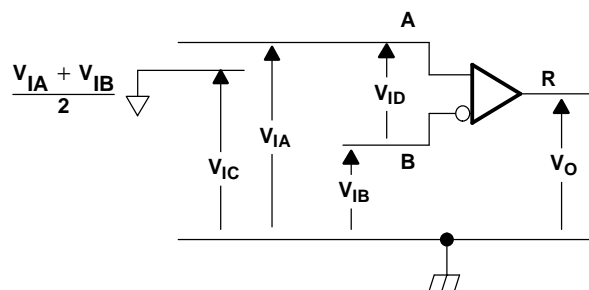


Figure 2. Receiver Voltage Definitions

Table 1. Receiver Minimum and Maximum Input Threshold Test Voltages

| APPLIED VOLTAGE | | RESULTING DIFFERENTIAL INPUT VOLTAGE | RESULTING COMMON-MODE INPUT VOLTAGE |
|-----------------|----------|--------------------------------------|-------------------------------------|
| V_{IA} | V_{IB} | V_{ID} | V_{IC} |
| 1.25 V | 1.15 V | 100 mV | 1.2 V |
| 1.15 V | 1.25 V | -100 mV | 1.2 V |
| 2.4 V | 2.3 V | 100 mV | 2.35 V |
| 2.3 V | 2.4 V | -100 mV | 2.35 V |
| 0.1 V | 0 V | 100 mV | 0.05 V |
| 0 V | 0.1 V | -100 mV | 0.05 V |
| 1.5 V | 0.9 V | 600 mV | 1.2 V |
| 0.9 V | 1.5 V | -600 mV | 1.2 V |
| 2.4 V | 1.8 V | 600 mV | 2.1 V |
| 1.8 V | 2.4 V | -600 mV | 2.1 V |
| 0.6 V | 0 V | 600 mV | 0.3 V |
| 0 V | 0.6 V | -600 mV | 0.3 V |

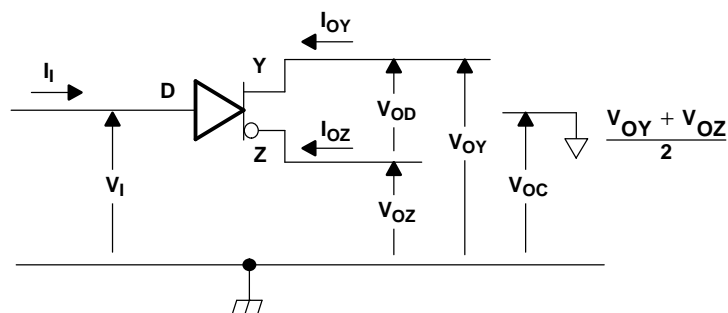
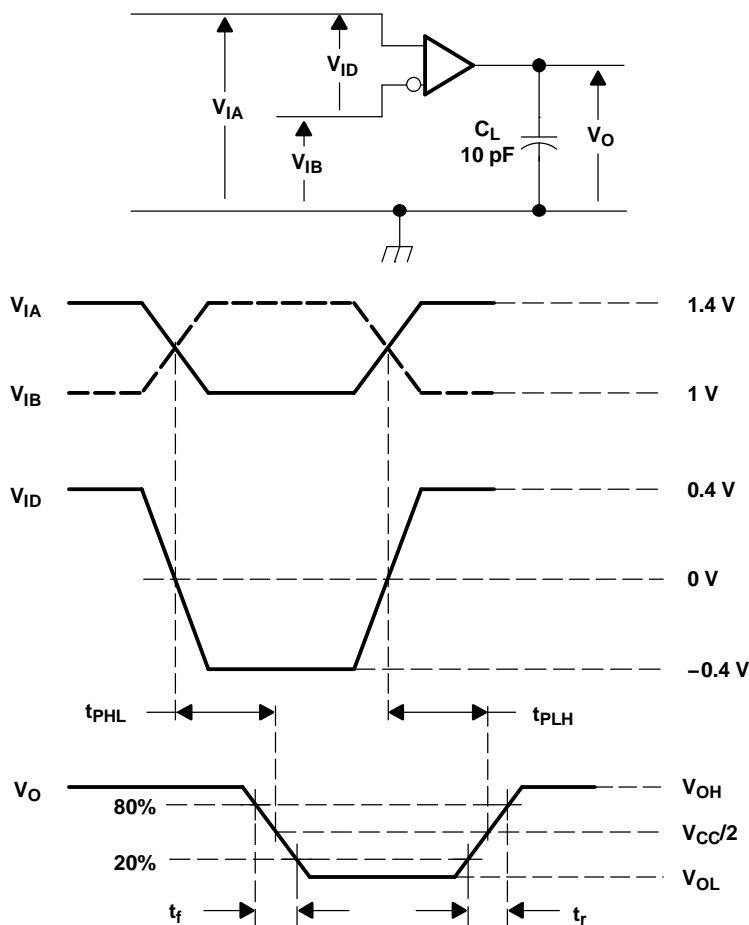


Figure 3. Driver Voltage and Current Definitions

PARAMETER MEASUREMENT INFORMATION



- A. All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1 \text{ ns}$, pulse repetition rate (PRR) = 1 Mpps, pulse width = $0.5 \pm 0.05 \text{ } \mu\text{s}$. C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

Figure 4. Receiver Timing Test Circuit and Waveforms

PARAMETER MEASUREMENT INFORMATION

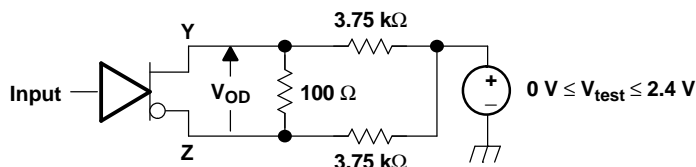
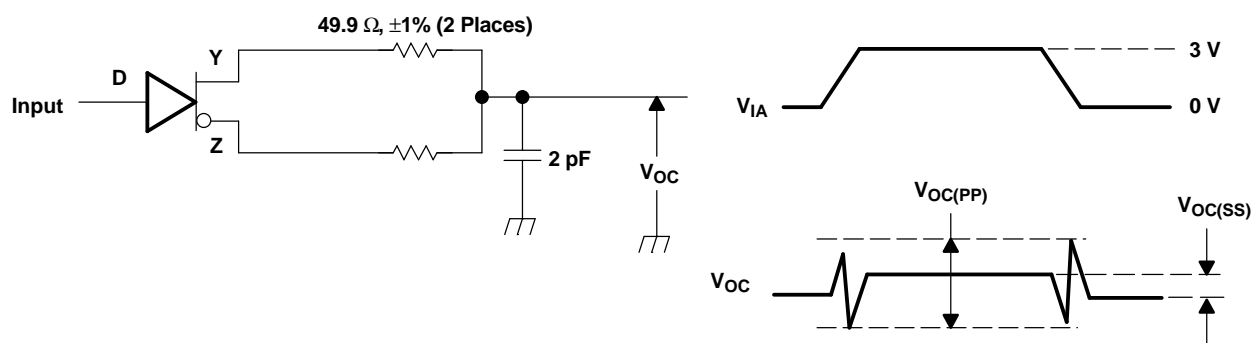
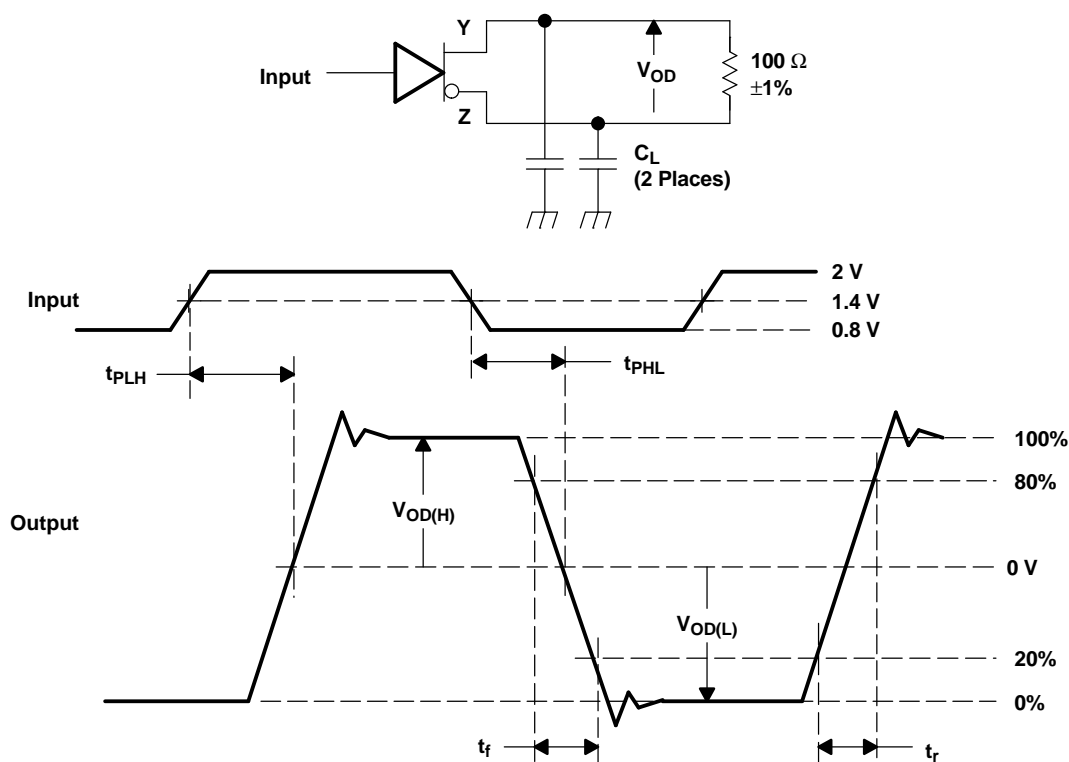


Figure 5. Driver VDO Test Circuit



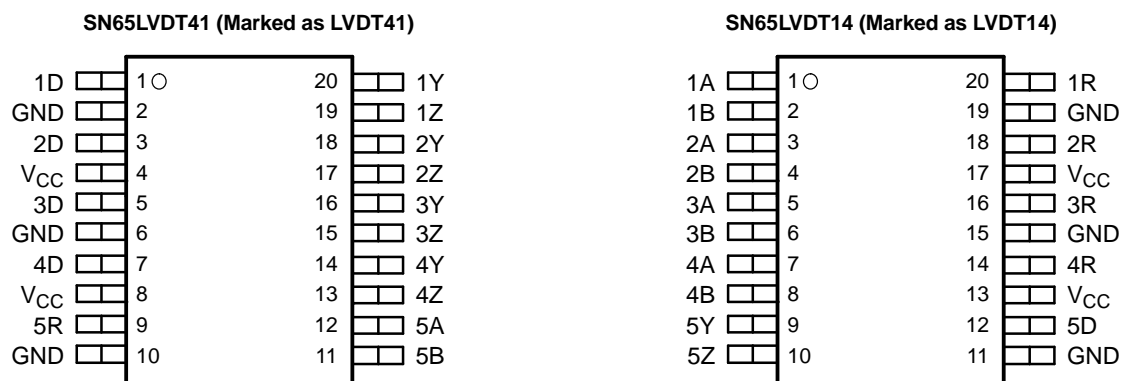
- A. All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1$ ns, pulse repetition rate (PRR) = 0.5 Mpps, pulse width = 500 ± 10 μ s. C_L includes instrumentation and fixture capacitance within 0.06 mm of the D.U.T. The measurement of $V_{OC(PP)}$ is made on test equipment with a –3-dB bandwidth of at least 1 GHz.

Figure 6. Test Circuit and Definitions for Driver Common-Mode Output Voltage



- A. All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1$ ns, pulse repetition rate (PRR) = 1 Mpps, pulse width = 0.5 ± 0.05 μ s. C_L includes instrumentation and fixture capacitance within 0.06 mm of the D.U.T.

Figure 7. Test Circuit, Timing, and Voltage Definitions for Differential Output Signal



FUNCTION TABLES

RECEIVER⁽¹⁾

| INPUTS | OUTPUT R |
|---|-------------|
| $V_{ID} = V_A - V_B$ | |
| $V_{ID} \geq 100 \text{ mV}$ | H |
| $-100 \text{ mV} < V_{ID} < 100 \text{ mV}$ | ? |
| $V_{ID} \leq -100 \text{ mV}$ | L |
| Open | H |

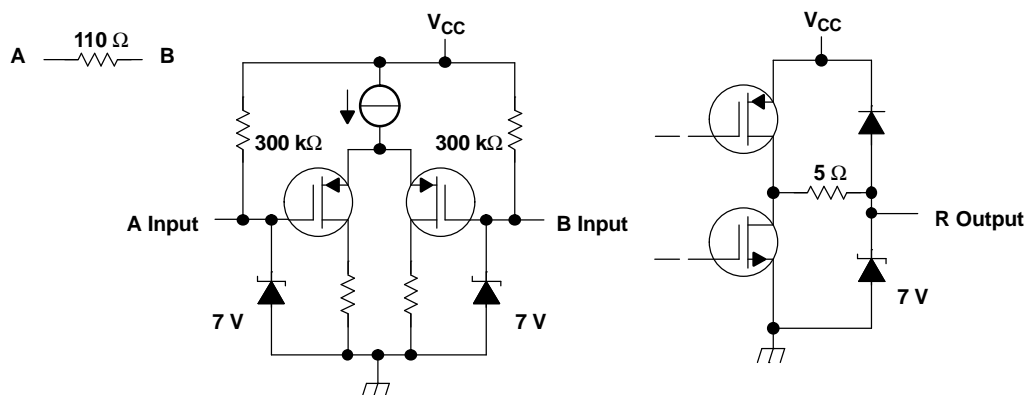
(1) H = high level, L = low level,
? = indeterminate

DRIVER⁽¹⁾

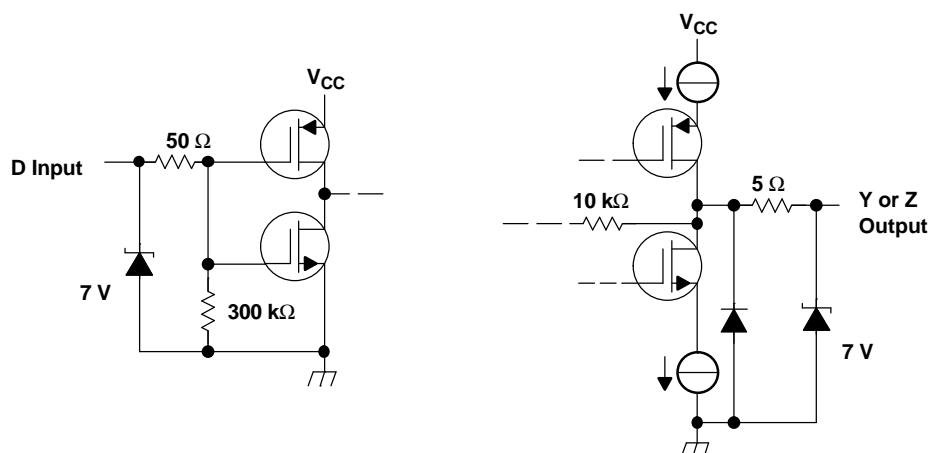
| INPUT D | OUTPUTS | |
|------------|---------|---|
| | Y | Z |
| H | H | L |
| L | L | H |
| Open | L | H |

(1) H = high level, L = low level

RECEIVER EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS



DRIVER EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS



TYPICAL CHARACTERISTICS Receiver

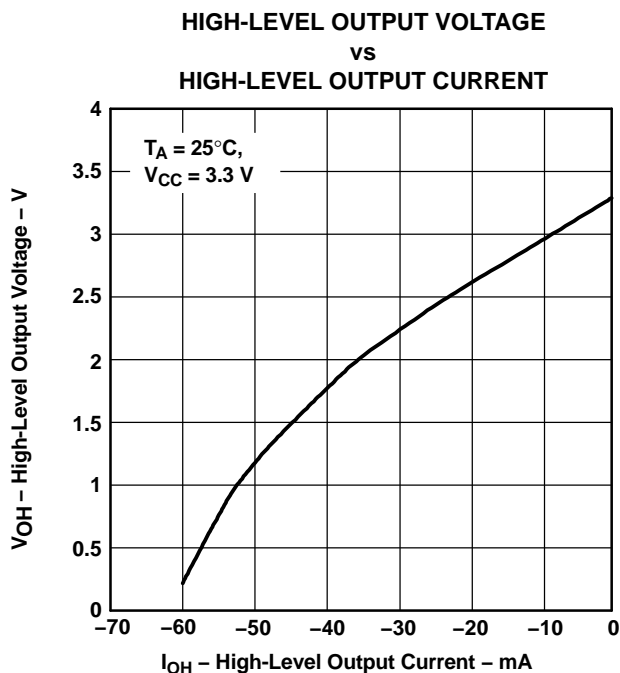


Figure 8.

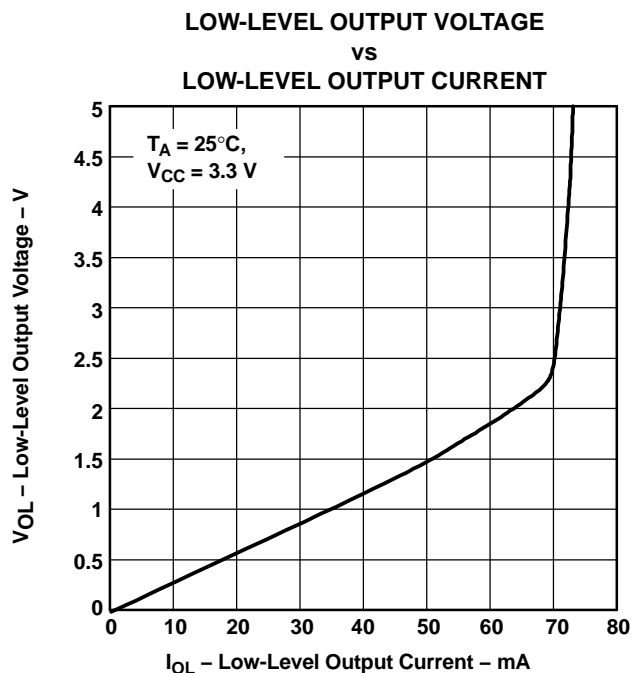


Figure 9.

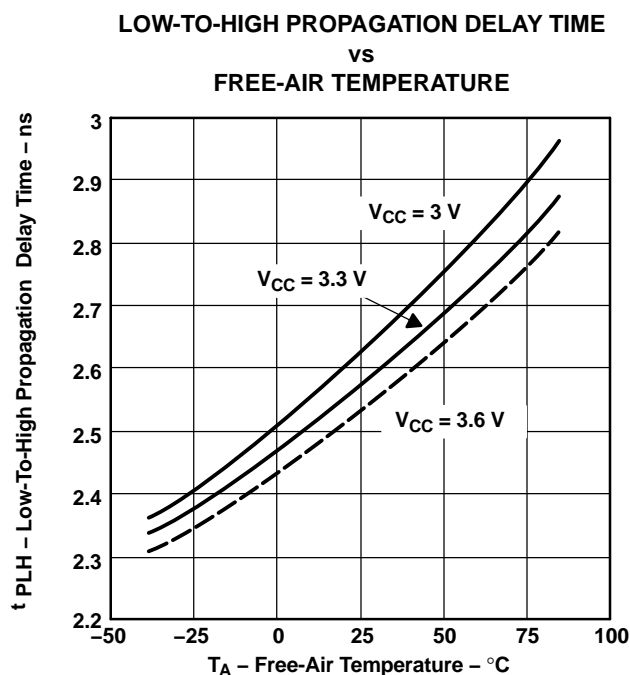


Figure 10.

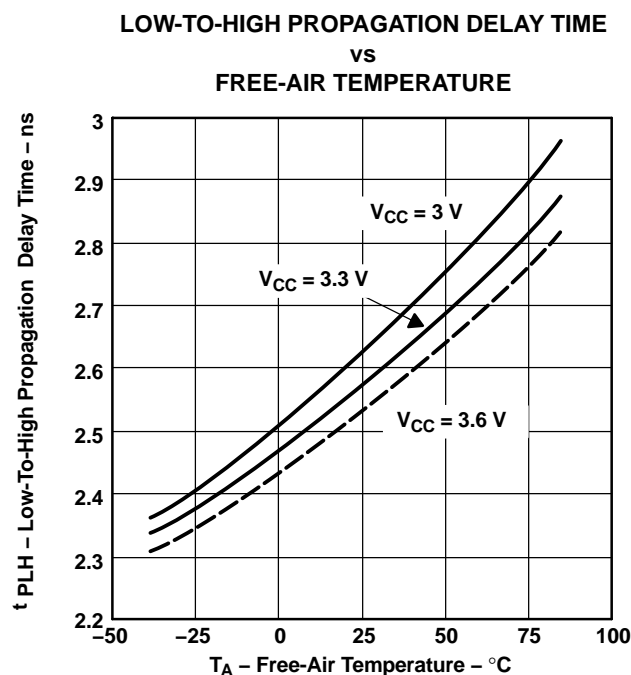


Figure 11.

TYPICAL CHARACTERISTICS
Driver

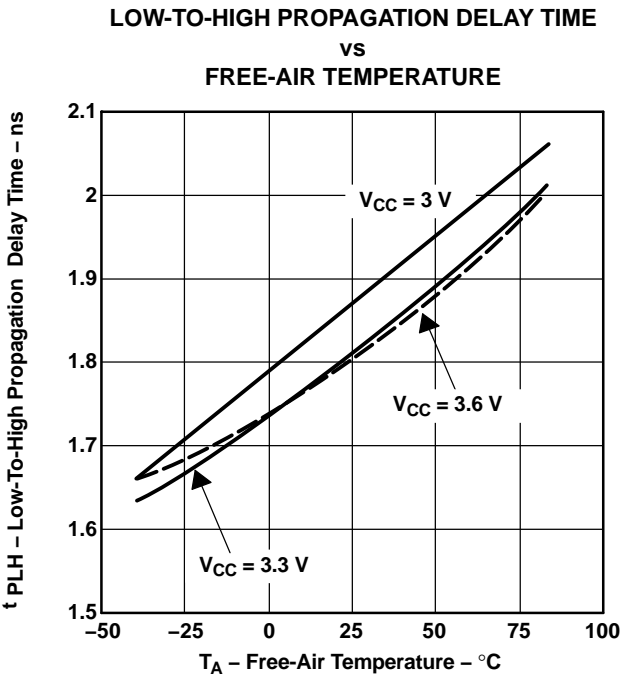


Figure 12.

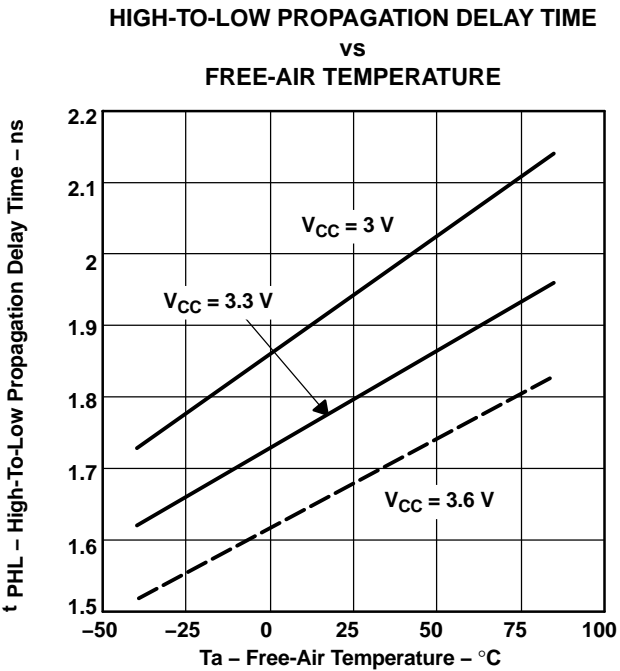


Figure 13.

APPLICATION INFORMATION

Extending the Memory Stick Interface Using LVDS Signaling Over Differential Transmission Cables

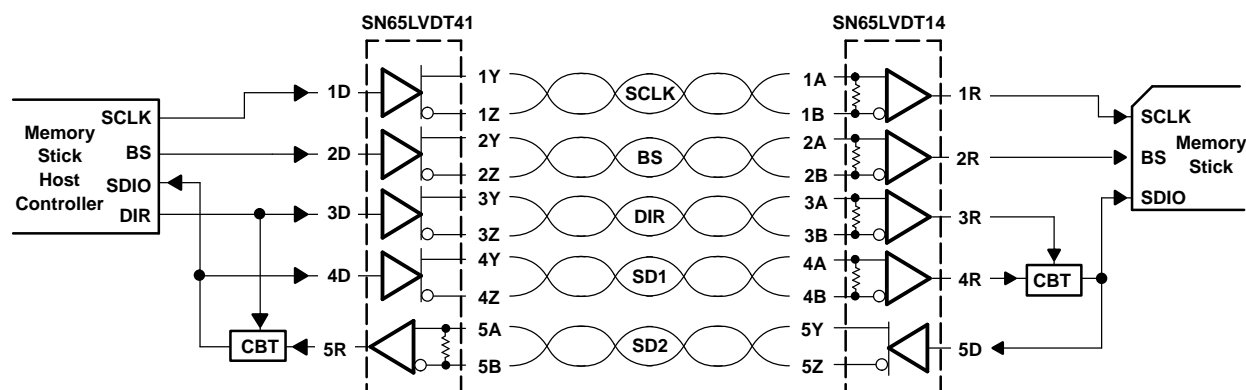


Figure 14. System-Level Block Diagram

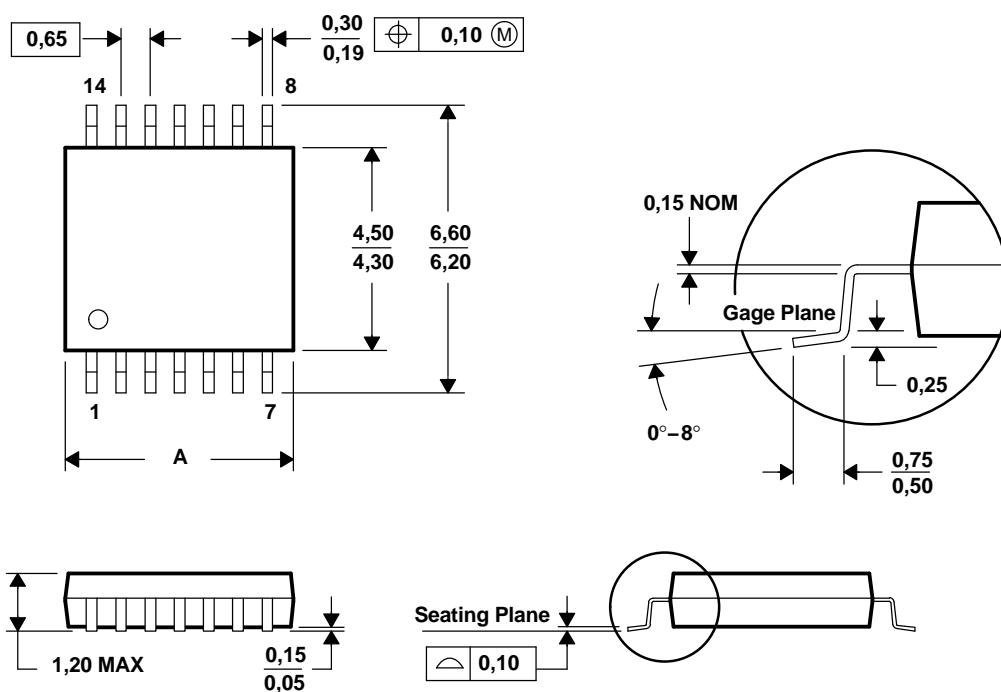
The Memory Stick signaling interface operates in a master-slave architecture, with three active signal lines. The host (master) supplies a clock (SCLK) and bus-state (BS) signal to control the operation of the system. The SCLK and BS signals are unidirectional (simplex) from the host to the Memory Stick. The serial data input/output (SDIO) signal is a bidirectional (half-duplex) signal used to communicate both control and data information between the host and the Memory Stick. The direction of data control is managed by the host through a combination of BS line states and control information delivered to the Memory Stick.

The basic Memory Stick interface is capable of operating only over short distances due to the single-ended nature of the digital I/O signals. Such a configuration is entirely suitable for compact and portable devices where there is little if any separation between the host and the Memory Stick. In applications where a greater distance is needed between the host controller and the Memory Stick, it is necessary to utilize a different signaling method, such as low-voltage differential signaling, or LVDS.

LVDS, as specified by the TIA/EIA-644-A standard, provides several benefits when compared to alternative long-distance signaling technologies: low radiated emissions, high noise immunity, low power consumption, and inexpensive interconnect cables.

This device pair provides the necessary LVDS drivers and receivers specifically targeted at implementing a Memory Stick interconnect extension. It utilizes simplex links for the SCLK and BS signals and two simplex links for the SDIO data. The half-duplex SDIO data is split into two simplex streams under control of the host processor by means of the direction (DIR) signal. The DIR signal also is carried from the host to the Memory Stick on a simplex LVDS link.

The switching of the SDIO signal-flow direction in the single-ended interfaces is managed by electronic switch devices, identified by the CBT symbol in Figure 7. A suggested CBT device for this application is the TI SN74CBTLV1G125. These devices are available in space-saving SOT-23 or SC-70 packages.

MECHANICAL DATA**PW (R-PDSO-G**)****PLASTIC SMALL-OUTLINE PACKAGE****14 PINS SHOWN**

| PINS ** DIM | 8 | 14 | 16 | 20 | 24 | 28 |
|----------------|------|------|------|------|------|------|
| A MAX | 3,10 | 5,10 | 5,10 | 6,60 | 7,90 | 9,80 |
| A MIN | 2,90 | 4,90 | 4,90 | 6,40 | 7,70 | 9,60 |

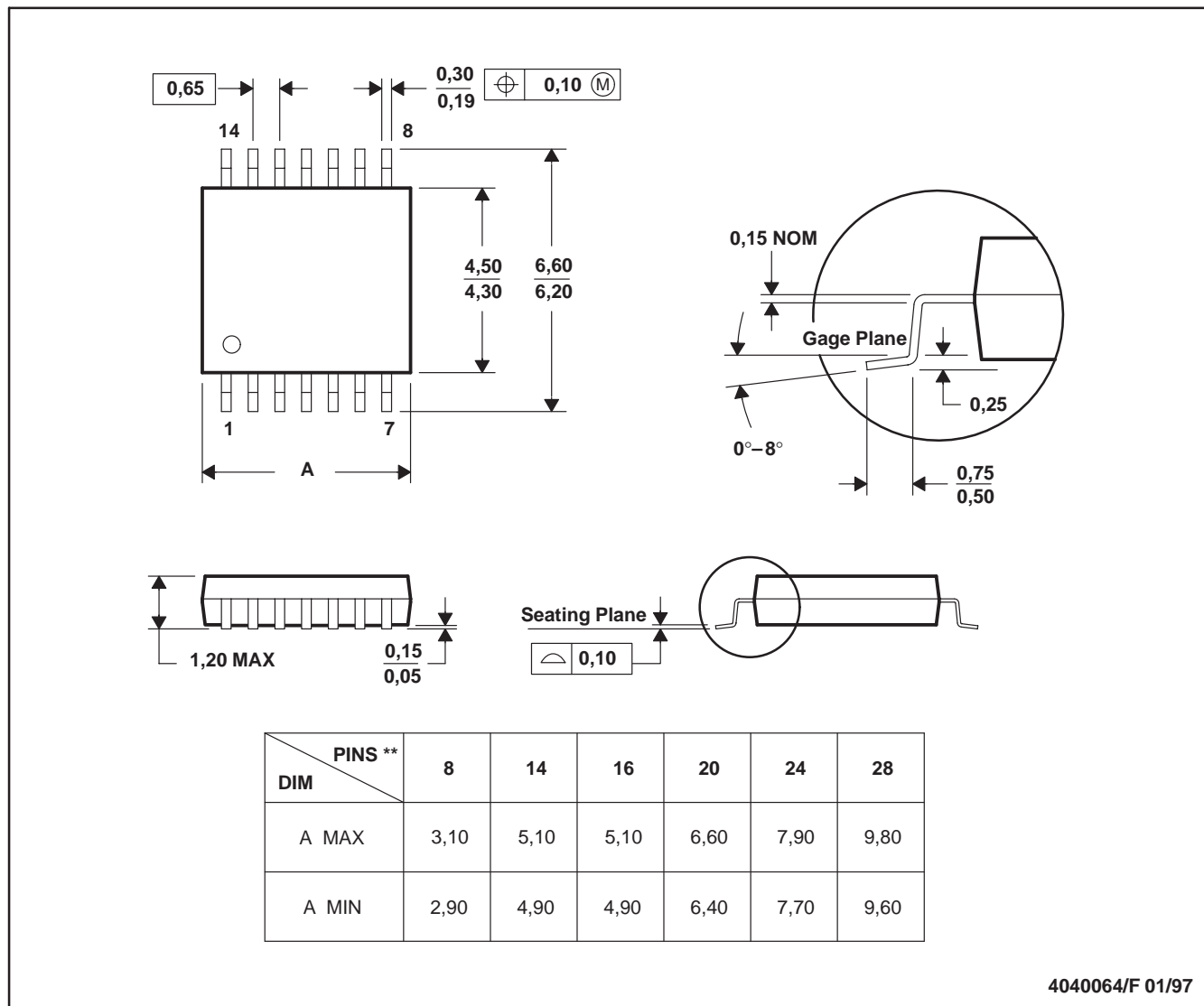
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- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
 D. Falls within JEDEC MO-153

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